ELSEVIER

Nuclear Instruments and Methods in Physics Research B 159 (1999) 257–261

NIM B
Beam Interactions with Materials & Atoms

www.elsevier.nl/locate/nimb

Author index

Amemiya, K., H. Takahashi, M. Nakazawa, N. Yasuda, M. Yamamoto, Y. Nakagawa, T. Kageji, M. Nakaichi and K. Ogura, Ultra-high resolution radiography using CR-39 solid state track detectors and atomic force microscopy . . . 159 (1999) 75
Andersson, M., see Zhang, Y. . . . 159 (1999) 142
Auble, R.L., see Welton, R.F. . . . 159 (1999) 116
Avasthi, A.M., see Biswas, A. . . . 159 (1999) 40
Avasthi, D.K., see Biswas, A. . . . 159 (1999) 40
Azuma, T., see Kudo, H. . . . 159 (1999) 241

Ballarini, F., see Biaggi, M. . . . 159 (1999) 89
Bamblevski, V.P., see Golovchenko, A.N. . . . 159 (1999) 233
Barbier, A., see Baudoing-Savois, R. . . . 159 (1999) 120
Barski, A., see Baudoing-Savois, R. . . . 159 (1999) 120
Baudoing-Savois, R., G. Renaud, M. De Santis, A. Barbier, O. Robach, P. Taunier, P. Jeantet, O. Ulrich, J.P. Roux, M.C. Saint-Lager, A. Barski, O. Geaymond, G. Bérard, P. Dolle, M. Noblet and A. Mougin, Erratum to: "A new UHV diffractometer for surface structure and real time molecular beam deposition studies with synchrotron radiations at ESRF" [Nucl. Instr. and Meth. B 149 (1999) 213] . . . 159 (1999) 120
Beene, J.R., see Welton, R.F. . . . 159 (1999) 116
Beijers, J.P.M., M.C. Duijvestijn, H. Fraiquin, J. van Klinken and R.W. Ostendorf, Separation of proton-induced fission isotopes from dominant evaporation residues by adapted target stacking. . . . 159 (1999) 176
Bérard, G., see Baudoing-Savois, R. . . . 159 (1999) 120
Biaggi, M., F. Ballarini, W. Burkard, E. Egger, A. Ferrari and A. Ottolenghi, Physical and biophysical characteristics of a fully modulated 72 MeV therapeutic proton beam: model predictions and experimental data . . . 159 (1999) 89
Bimbot, R., see Golovchenko, A.N. . . . 159 (1999) 233
Biswas, A., S. Lotha, D. Fink, J.P. Singh, D.K. Avasthi, B.K. Yadav, S.K. Bose, D.T. Khating and A.M. Avasthi, The effects of swift heavy ion irradiation on the radiochemistry and melting characteristics of PET . . . 159 (1999) 40
Blackmon, J.C., see Welton, R.F. . . . 159 (1999) 116
Bose, S.K., see Biswas, A. . . . 159 (1999) 40
Breese, M.B.H., D.G. de Kerckhove, P.J.M. Smulders and D.N. Jamieson, A study of the relationship between spatial and angular coordinates of axially channeled MeV protons . . . 159 (1999) 248
Burkard, W., see Biaggi, M. . . . 159 (1999) 89

Chang, Y.C., see Lee, C.S. . . . 159 (1999) 201
Chang, Y.H., see Lee, C.S. . . . 159 (1999) 201
Chen, C.-M., H.C. Pan, D.Z. Zhu, J. Hu and M.Q. Li, Cathodoluminescence and ion beam analysis of ion-implanted combinatorial materials libraries on thermally grown SiO_2 . . . 159 (1999) 81
Chiari, M., see Mazzoni, S. . . . 159 (1999) 191

de Kerckhove, D.G., see Breese, M.B.H. . . . 159 (1999) 248
De Santis, M., see Baudoing-Savois, R. . . . 159 (1999) 120
Dolle, P., see Baudoing-Savois, R. . . . 159 (1999) 120

0168-583X/99/$ – see front matter © 1999 Elsevier Science B.V. All rights reserved
PII: S0168-583X(99)00638-2

Duijvestijn, M.C., see Beijers, J.P.M. 159 (1999) 176

Egger, E., see Biaggi, M. 159 (1999) 89
Ezz-Eldin, F.M., Radiation effects on some physical and thermal properties of V_2O_5–P_2O_5 glasses 159 (1999) 166

Fedotova, J.A., see Uglov, V.V. 159 (1999) 218
Ferrari, A., see Biaggi, M. 159 (1999) 89
Fink, D., see Biswas, A. 159 (1999) 40
Fraiquin, H., see Beijers, J.P.M. 159 (1999) 176

Gawlik, G., see Uglov, V.V. 159 (1999) 218
Geaymond, O., see Baudoing-Savois, R. 159 (1999) 120
Giuntini, L., see Mazzoni, S. 159 (1999) 191
Golovchenko, A.N., J. Skvarč, R. Ilić, L. Sihver, V.P. Bamblevski, S.P. Tretyakova, D. Schardt, R.K. Tripathi, J.W. Wilson and R. Bimbot, Fragmentation of 200 and 244 MeV/u carbon beams in thick tissue-like absorbers 159 (1999) 233
Goriletsky, V.I., B.V. Grinyov, A.M. Panova, K.V. Shakhova, E.L. Vinograd and S.P. Korsunov, Kinetic and scintillation characteristics of CsI(Na) crystals grown under melt mixing 159 (1999) 111
Graczyk, M., see Zhang, Y. 159 (1999) 133
Graczyk, M., see Zhang, Y. 159 (1999) 142
Graczyk, M., see Zhang, Y. 159 (1999) 158
Grinyov, B.V., see Goriletsky, V.I. 159 (1999) 111
Gupta-Bhaya, P., see Som, T. 159 (1999) 67

Hazdra, P., J. Rubeš and J. Vobecký, Divacancy profiles in MeV helium irradiated silicon from reverse I–V measurement 159 (1999) 207
Hu, J., see Chen, C.-M. 159 (1999) 81

Ilić, R., see Golovchenko, A.N. 159 (1999) 233
Itoh, A., H. Tsuchida, T. Majima, A. Yogo and A. Ogawa, Equilibrium charge distributions of lithium ions emerging from a carbon foil 159 (1999) 22

Jagielski, J., see Uglov, V.V. 159 (1999) 218
Jamieson, D.N., see Breese, M.B.H. 159 (1999) 248
Jeantet, P., see Baudoing-Savois, R. 159 (1999) 120

Kageji, T., see Amemiya, K. 159 (1999) 75
Karolewski, M.A., Classical dynamics simulations of 4 keV Ar sputtering of Ca(1 0 0) 159 (1999) 28
Khan, T.K., see Som, T. 159 (1999) 67
Khating, D.T., see Biswas, A. 159 (1999) 40
Kitoba, U., see Shiomi-Tsuda, N. 159 (1999) 123
Klein, J. and R. Middleton, Observation of BeC_n^{2-}, a particularly abundant gaseous dianion 159 (1999) 8
Kormicki, J., see Welton, R.F. 159 (1999) 116
Korsunov, S.P., see Goriletsky, V.I. 159 (1999) 111
Kothari, D.C., see Sinha, S.K. 159 (1999) 227
Kudo, H., K. Shibuya, N. Nakamura, T. Azuma and S. Seki, Forward scattering peaks of ion-induced Auger electrons 159 (1999) 241
Kulkarni, V.N., see Sinha, S.K. 159 (1999) 227
Kulkarni, V.N., see Som, T. 159 (1999) 67
Kumar, S., see Som, T. 159 (1999) 67
Kuronen, A., see Nordlund, K. 159 (1999) 183

Lee, C.S., Y.C. Chang and Y.H. Chang, Light emissions from sputtered particles produced during ion bombardment of Al(111) and polycrystalline Al surfaces 159 (1999) 201
Leech, P.W. and M.C. Ridgway, Effect of MeV O^{2+} implantation on the reactive ion etch rate of $LiTaO_3$ . . 159 (1999) 187
Lefterov, D., see Ruskov, T. 159 (1999) 60
Li, M.Q., see Chen, C.-M. 159 (1999) 81

Lotha, S., see Biswas, A. 159 (1999) 40

Majima, T., see Itoh, A. 159 (1999) 22
Mandò, P.A., see Mazzoni, S. 159 (1999) 191
Maximov, I.A., see Zhang, Y. 159 (1999) 133
Maximov, I.A., see Zhang, Y. 159 (1999) 142
Maximov, I.A., see Zhang, Y. 159 (1999) 158
Mazzoni, S., M. Chiari, L. Giuntini, P.A. Mandò and N. Taccetti, Erratum to: "Proton elastic scattering cross-section on carbon from 350 keV to 3 MeV" [Nucl. Instr. and Meth. B 136–138 (1998) 86–90]. . . . 159 (1999) 191
Middleton, R., see Klein, J. 159 (1999) 8
Moneta, M., Energy loss and straggling of slow ions in electron gas 159 (1999) 1
Montelius, L., see Zhang, Y. 159 (1999) 133
Montelius, L., see Zhang, Y. 159 (1999) 142
Montelius, L., see Zhang, Y. 159 (1999) 158
Mougin, A., see Baudoing-Savois, R. 159 (1999) 120
Mueller, P.E., see Welton, R.F. 159 (1999) 116

Nair, K.G.M., see Sinha, S.K. 159 (1999) 227
Nakagawa, Y., see Amemiya, K. 159 (1999) 75
Nakaichi, M., see Amemiya, K. 159 (1999) 75
Nakamura, N., see Kudo, H. 159 (1999) 241
Nakazawa, M., see Amemiya, K. 159 (1999) 75
Noblet, M., see Baudoing-Savois, R. 159 (1999) 120
Nordlund, K. and A. Kuronen, Non-equilibrium properties of GaAs interatomic potentials 159 (1999) 183

Ogawa, A., see Itoh, A. 159 (1999) 22
Ogawa, H., see Shiomi-Tsuda, N. 159 (1999) 123
Ogura, K., see Amemiya, K. 159 (1999) 75
Ostendorf, R.W., see Beijers, J.P.M. 159 (1999) 176
Ottolenghi, A., see Biaggi, M. 159 (1999) 89

Pan, H.C., see Chen, C.-M. 159 (1999) 81
Panchapakesan, S., see Sinha, S.K. 159 (1999) 227
Paneva, D., see Ruskov, T. 159 (1999) 60
Panova, A.M., see Goriletsky, V.I. 159 (1999) 111
Porter, L.E., Values of modified Bethe–Bloch stopping power parameters for polysulfone extracted from stopping power measurements with light projectiles 159 (1999) 195

Renaud, G., see Baudoing-Savois, R. 159 (1999) 120
Ridgway, M.C., see Leech, P.W. 159 (1999) 187
Robach, O., see Baudoing-Savois, R. 159 (1999) 120
Roux, J.P., see Baudoing-Savois, R. 159 (1999) 120
Rubeš, J., see Hazdra, P. 159 (1999) 207
Rudy, A.S. and V.K. Smirnov, Hydrodynamic model of wave-ordered structures formed by ion bombardment of solids. 159 (1999) 52
Ruskov, R., see Ruskov, T. 159 (1999) 60
Ruskov, T., R. Ruskov, D. Paneva and D. Lefterov, Contribution of back-scattered electromagnetic rays to the Mössbauer conversion electron spectrum. 159 (1999) 60

Saint-Lager, M.C., see Baudoing-Savois, R. 159 (1999) 120
Sakamoto, N., see Shiomi-Tsuda, N. 159 (1999) 123
Sarwe, E.-L., see Zhang, Y. 159 (1999) 133
Sarwe, E.-L., see Zhang, Y. 159 (1999) 142
Sarwe, E.-L., see Zhang, Y. 159 (1999) 158
Schardt, D., see Golovchenko, A.N. 159 (1999) 233
Seki, S., see Kudo, H. 159 (1999) 241
Shakhova, K.V., see Goriletsky, V.I. 159 (1999) 111

Shibuya, K., see Kudo, H. 159 (1999) 241
Shiomi-Tsuda, N., N. Sakamoto, H. Ogawa and U. Kitoba, Stopping powers of Al and Mo for protons from 0.3 to 3.0 MeV 159 (1999) 123
Sihver, L., see Golovchenko, A.N. 159 (1999) 233
Singh, J.P., see Biswas, A. 159 (1999) 40
Sinha, S.K., D.C. Kothari, K.M. Vigen, T. Som, V.N. Kulkarni, S. Panchapakesan and K.G.M. Nair, Ion beam mixing of Fe with alumina: RBS studies 159 (1999) 227
Skvarč, J., see Golovchenko, A.N. 159 (1999) 233
Smirnov, V.K., see Rudy, A.S. 159 (1999) 52
Smulders, P.J.M., see Breese, M.B.H. 159 (1999) 248
Som, T., see Sinha, S.K. 159 (1999) 227
Som, T., T.K. Khan, P. Gupta-Bhaya, S. Kumar and V.N. Kulkarni, Ion-beam analysis of phospholipid thin films deposited on c-Si 159 (1999) 67
Stanek, J., see Uglov, V.V. 159 (1999) 218
Stracener, D.W., see Welton, R.F. 159 (1999) 116

Taccetti, N., see Mazzoni, S. 159 (1999) 191
Takahashi, H., see Amemiya, K. 159 (1999) 75
Taunier, P., see Baudoing-Savois, R. 159 (1999) 120
Tretyakova, S.P., see Golovchenko, A.N. 159 (1999) 233
Tripathi, R.K., see Golovchenko, A.N. 159 (1999) 233
Tsuchida, H., see Itoh, A. 159 (1999) 22

Uglov, V.V., J.A. Fedotova, J. Jagielski, G. Gawlik and J. Stanek, Transformation of amorphous a-(Fe–B) phase during nitrogen implantation 159 (1999) 218
Ulrich, O., see Baudoing-Savois, R. 159 (1999) 120

van Klinken, J., see Beijers, J.P.M. 159 (1999) 176
Vigen, K.M., see Sinha, S.K. 159 (1999) 227
Vinograd, E.L., see Goriletsky, V.I. 159 (1999) 111
Vobecký, J., see Hazdra, P. 159 (1999) 207

Welton, R.F., R.L. Auble, J.R. Beene, J.C. Blackmon, J. Kormicki, P.E. Mueller, D.W. Stracener and C.L. Williams, A new technique for the production of ^{17}F beams (*Letter to the Editor*) 159 (1999) 116
Whitlow, H.J., see Zhang, Y. 159 (1999) 101
Whitlow, H.J., see Zhang, Y. 159 (1999) 133
Whitlow, H.J., see Zhang, Y. 159 (1999) 142
Whitlow, H.J., see Zhang, Y. 159 (1999) 158
Williams, C.L., see Welton, R.F. 159 (1999) 116
Wilson, J.W., see Golovchenko, A.N. 159 (1999) 233
Winzell, T., see Zhang, Y. 159 (1999) 101
Winzell, T., see Zhang, Y. 159 (1999) 133
Winzell, T., see Zhang, Y. 159 (1999) 142
Winzell, T., see Zhang, Y. 159 (1999) 158

Yadav, B.K., see Biswas, A. 159 (1999) 40
Yamamoto, M., see Amemiya, K. 159 (1999) 75
Yasuda, N., see Amemiya, K. 159 (1999) 75
Yogo, A., see Itoh, A. 159 (1999) 22

Zhang, T., see Zhang, Y. 159 (1999) 133
Zhang, T., see Zhang, Y. 159 (1999) 142
Zhang, T., see Zhang, Y. 159 (1999) 158
Zhang, Y., T. Winzell and H.J. Whitlow, The response and calibration of thin Si ΔE detectors. 159 (1999) 101
Zhang, Y., T. Winzell, T. Zhang, I.A. Maximov, E.-L. Sarwe, M. Graczyk, L. Montelius and H.J. Whitlow, High-fluence Co implantation in Si, SiO_2/Si and Si_3N_4/Si. Part II: sputtering yield transients, the approach to high-fluence equilibrium 159 (1999) 133

Zhang, Y., T. Winzell, T. Zhang, I.A. Maximov, E.-L. Sarwe, M. Graczyk, L. Montelius and H.J. Whitlow, High-fluence Co implantation in Si, SiO_2/Si and Si_3N_4/Si. Part III: heavy-fluence Co bombardment induced surface topography development 159 (1999) 158
Zhang, Y., T. Winzell, T. Zhang, M. Andersson, I.A. Maximov, E.-L. Sarwe, M. Graczyk, L. Montelius and H.J. Whitlow, High-fluence Co implantation in Si, SiO_2/Si and Si_3N_4/Si. Part I: formation of thin silicide surface films. 159 (1999) 142
Zhu, D.Z., see Chen, C.-M.. . . . . 159 (1999) 81

Nuclear Instruments and Methods in Physics Research B 159 (1999) 263–264

ELSEVIER

NIM B
Beam Interactions with Materials & Atoms

www.elsevier.nl/locate/nimb

Subject index

Basic Data for Materials Modification and Analysis

Energy loss and straggling of slow ions in electron gas, M. Moneta 152 (1999) 1
Observation of BeC_n^{2-}, a particularly abundant gaseous dianion, J. Klein and R. Middleton 152 (1999) 8
Stopping powers of Al and Mo for protons from 0.3 to 3.0 MeV, N. Shiomi-Tsuda, N. Sakamoto, H. Ogawa and U. Kitoba 152 (1999) 123
Non-equilibrium properties of GaAs interatomic potentials, K. Nordlund and A. Kuronen (*Letter to the Editor*) 152 (1999) 183
Values of modified Bethe–Bloch stopping power parameters for polysulfone extracted from stopping power measurements with light projectiles, L.E. Porter 152 (1999) 195

Atomic Collisions in Solids

Equilibrium charge distributions of lithium ions emerging from a carbon foil, A. Itoh, H. Tsuchida, T. Majima, A. Yogo and A. Ogawa 152 (1999) 22
Classical dynamics simulations of 4 keV Ar sputtering of Ca(1 0 0), M.A. Karolewski 152 (1999) 28
High-fluence Co implantation in Si, SiO_2/Si and Si_3N_4/Si. Part II: sputtering yield transients, the approach to high-fluence equilibrium, Y. Zhang, T. Winzell, T. Zhang, I.A. Maximov, E.-L. Sarwe, M. Graczyk, L. Montelius and H.J. Whitlow 152 (1999) 133
Light emissions from sputtered particles produced during ion bombardment of Al(111) and polycrystalline Al surfaces, C.S. Lee, Y.C. Chang and Y.H. Chang 152 (1999) 201
A study of the relationship between spatial and angular coordinates of axially channeled MeV protons, M.B.H. Breese, D.G. de Kerckhove, P.J.M. Smulders and D.N. Jamieson (*Letter to the Editor*) 152 (1999) 248

Ion Beam Modification of Materials

The effects of swift heavy ion irradiation on the radiochemistry and melting characteristics of PET, A. Biswas, S. Lotha, D. Fink, J.P. Singh, D.K. Avasthi, B.K. Yadav, S.K. Bose, D.T. Khating and A.M. Avasthi 152 (1999) 40
High-fluence Co implantation in Si, SiO_2/Si and Si_3N_4/Si. Part I: formation of thin silicide surface films, Y. Zhang, T. Winzell, T. Zhang, M. Andersson, I.A. Maximov, E.-L. Sarwe, M. Graczyk, L. Montelius and H.J. Whitlow 152 (1999) 142
Effect of MeV O^{2+} implantation on the reactive ion etch rate of $LiTaO_3$, P.W. Leech and M.C. Ridgway (*Letter to the Editor*) 152 (1999) 187
Divacancy profiles in MeV helium irradiated silicon from reverse I–V measurement, P. Hazdra, J. Rubeš and J. Vobecký 152 (1999) 207
Transformation of amorphous a-(Fe–B) phase during nitrogen implantation, V.V. Uglov, J.A. Fedotova, J. Jagielski, G. Gawlik and J. Stanek 152 (1999) 218
Ion beam mixing of Fe with alumina: RBS studies, S.K. Sinha, D.C. Kothari, K.M. Vigen, T. Som, V.N. Kulkarni, S. Panchapakesan and K.G.M. Nair 152 (1999) 227

Effects of Radiation

Hydrodynamic model of wave-ordered structures formed by ion bombardment of solids, A.S. Rudy and V.K. Smirnov 152 (1999) 52
High-fluence Co implantation in Si, SiO_2/Si and Si_3N_4/Si. Part III: heavy-fluence Co bombardment induced surface topography development, Y. Zhang, T. Winzell, T. Zhang, I.A. Maximov, E.-L. Sarwe, M. Graczyk, L. Montelius and H.J. Whitlow 152 (1999) 158

0168-583X/99/$ – see frontmatter © 1999 Elsevier Science B.V. All rights reserved.
PII: S0168-583X(99)00639-4

Radiation effects on some physical and thermal properties of V_2O_5–P_2O_5 glasses, F.M. Ezz-Eldin 152 (1999) 166
Fragmentation of 200 and 244 MeV/u carbon beams in thick tissue-like absorbers, A.N. Golovchenko, J. Skvarč, R. Ilić, L. Sihver, V.P. Bamblevski, S.P. Tretyakova, D. Schardt, R.K. Tripathi, J.W. Wilson and R. Bimbot 152 (1999) 233

Analysis of Materials

Contribution of back-scattered electromagnetic rays to the Mössbauer conversion electron spectrum, T. Ruskov, R. Ruskov, D. Paneva and D. Lefterov 152 (1999) 60
Ion-beam analysis of phospholipid thin films deposited on c-Si, T. Som, T.K. Khan, P. Gupta-Bhaya, S. Kumar and V.N. Kulkarni 152 (1999) 67
Ultra-high resolution radiography using CR-39 solid state track detectors and atomic force microscopy, K. Amemiya, H. Takahashi, M. Nakazawa, N. Yasuda, M. Yamamoto, Y. Nakagawa, T. Kageji, M. Nakaichi and K. Ogura. 152 (1999) 75
Cathodoluminescence and ion beam analysis of ion-implanted combinatorial materials libraries on thermally grown SiO_2, C.-M. Chen, H.C. Pan, D.Z. Zhu, J. Hu and M.Q. Li 152 (1999) 81

Ion Sources and Beam Optics

Physical and biophysical characteristics of a fully modulated 72 MeV therapeutic proton beam: model predictions and experimental data, M. Biaggi, F. Ballarini, W. Burkard, E. Egger, A. Ferrari and A. Ottolenghi. 152 (1999) 89
A new technique for the production of ^{17}F beams, R.F. Welton, R.L. Auble, J.R. Beene, J.C. Blackmon, J. Kormicki, P.E. Mueller, D.W. Stracener and C.L. Williams (*Letter to the Editor*) 152 (1999) 116

Experimental Methods and Equipment

The response and calibration of thin Si ΔE detectors, Y. Zhang, T. Winzell and H.J. Whitlow 152 (1999) 101
Kinetic and scintillation characteristics of CsI(Na) crystals grown under melt mixing, V.I. Goriletsky, B.V. Grinyov, A.M. Panova, K.V. Shakhova, E.L. Vinograd and S.P. Korsunov 152 (1999) 111
Separation of proton-induced fission isotopes from dominant evaporation residues by adapted target stacking, J.P.M. Beijers, M.C. Duijvestijn, H. Fraiquin, J. van Klinken and R.W. Ostendorf 152 (1999) 176
Forward scattering peaks of ion-induced Auger electrons, H. Kudo, K. Shibuya, N. Nakamura, T. Azuma and S. Seki. 152 (1999) 241

Letters to the Editor

A new technique for the production of ^{17}F beams, R.F. Welton, R.L. Auble, J.R. Beene, J.C. Blackmon, J. Kormicki, P.E. Mueller, D.W. Stracener and C.L. Williams 152 (1999) 116
Non-equilibrium properties of GaAs interatomic potentials, K. Nordlund and A. Kuronen 152 (1999) 183
Effect of MeV O^{2+} implantation on the reactive ion etch rate of $LiTaO_3$, P.W. Leech and M.C. Ridgway 152 (1999) 187
A study of the relationship between spatial and angular coordinates of axially channeled MeV protons, M.B.H. Breese, D.G. de Kerckhove, P.J.M. Smulders and D.N. Jamieson. 152 (1999) 248

Errata

Erratum to: "A new UHV diffractometer for surface structure and real time molecular beam deposition studies with synchrotron radiations at ESRF" [Nucl. Instr. and Meth. B 149 (1999) 213], R. Baudoing-Savois, G. Renaud, M. De Santis, A. Barbier, O. Robach, P. Taunier, P. Jeantet, O. Ulrich, J.P. Roux, M.C. Saint-Lager, A. Barski, O. Geaymond, G. Bérard, P. Dolle, M. Noblet and A. Mougin 152 (1999) 120
Erratum to: "Proton elastic scattering cross-section on carbon from 350 keV to 3 MeV" [Nucl. Instr. and Meth. B 136–138 (1998) 86–90], S. Mazzoni, M. Chiari, L. Giuntini, P.A. Mandò and N. Taccetti. 152 (1999) 191